INFORM	INFORMATION DISCLOSURE CITATION			Attorney Docket No.: 46884-5429			Serial No.: 10/551,195		
(Use several sheets if necessary)			Applicants: Seiichi NAGATA			Page 1 of 1			
0 1008 B PTO Form 1449			Filing Date: April 27, 2007			Group Art Unit: 1794			
Examiner	τ	U.S. PATENT DOC	CUMENTS						
	Document	_			Class	Sub			
Initial	Number	Date 20		Name Moellendorf et al		Class			
	6,174,746 6,277,662	January 16, 20 August 21, 20		Nagata					
						 			
						 			
						 			
		-							
	· · · · · · · · · · · · · · · · · · ·			_		-	···		
	FOR	REIGN PATENT D	OCUMENTS						
	Document		1	<u> </u>	Sub		Translation		
	Number	Date	Country	Class	Class	YES	NO		
	WO 91/10931 WO 87/00684	July 25, 199 January 29, 19			 -				
	W 0 07/00004	Surday 25, 15	07 101						
	OTHER DOCUMENTS	Cincluding Author	Title Date Per	rtinent Pag	ves Etc.)	<u> </u>	<u> </u>		
		_				an of Calast	ivoly Dono		
	Seiichi Nagata, et al., " S Titanium Porous Silicon,' Institute of Physics, Melv	" Vol. 72, No. 23, Ji	ine 8, 1988, Ap	plied Phys	sics Letters	s, AIP, Ame	rican		
	R. Narendra, et al., "Sing No. 1, January 1993, IEE 46, ISSN: 1041-1135, XP	le-Mode, Phosphoru E Photonics Techno	s-Doped Silica	Waveguio	les in Silic	on V-Groov	ves," Vol. 5 NJ. Pgs. 4		
				b . c					
Examiner				Date Cons	sidered				
	f reference considered, whether						citation if		
not in c	onformance and not considered.	Include copy of thi	s form with nex	t commun	ication to	applicant.			